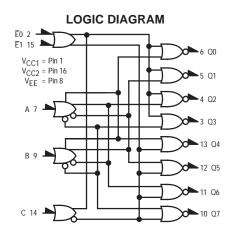
Binary to 1-8 Decoder (High)

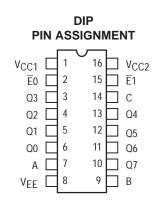
The MC10H162 provides parallel decoding of a three bit binary word to one of eight lines. The MC10H162 is useful in high–speed multiplexer/ demultiplexer applications.

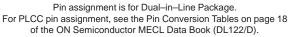
The MC10H162 is designed to decode a three bit input word to one of eight output lines. The MC10H162 output will be high when selected while all other output are low. The enable inputs, when either or both are high, force all outputs low.

The MC10H162 is a true parallel decoder. This eliminates unequal parallel path delay times found in other decoder designs. These devices are ideally suited for multiplexer/demultiplexer applications.

- Propagation Delay, 1.0 ns Typical
- Power Dissipation, 315 mW Typical (same as MECL 10K)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K–Compatible



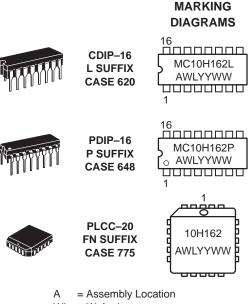






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A = Assembly Location WL = Wafer Lot YY = Year WW = Work Week

TRUTH TABLE												
INPUTS						OUTPUTS						
Ē0	Ē1	С	В	Α	Q0	Q1	Q2	Q3	Q4	Q5	Q6	Q7
L L	L –	L	L	L H	Н	L H	L	L	L	L	L	L
Ĺ	Ĺ	Ĺ	Ĥ	L	Ĺ	Ľ	Ĥ	Ĺ	Ĺ	Ĺ	Ĺ	Ĺ
L	L	L H	H L	H L	L	L	L	H L	L H	L	L	L
L		H H	L H	H	L	L	L	L	L	H	L H	L
Ľ	Ĺ	H	H	Ĥ	Ľ	Ĺ	L	L	Ĺ	L	Ľ	Ĥ
H X	X H	X X	X X	X X		L	L	L	L		L	L

ORDERING INFORMATION

Device	Package	Shipping		
MC10H162L	CDIP-16	25 Units/Rail		
MC10H162P	PDIP-16	25 Units/Rail		
MC10H162FN	PLCC-20	46 Units/Rail		

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply ($V_{CC} = 0$)	-8.0 to 0	Vdc
VI	Input Voltage (V _{CC} = 0)	0 to V _{EE}	Vdc
lout	Output Current – Continuous – Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range – Plastic – Ceramic	–55 to +150 –55 to +165	°C ℃

ELECTRICAL CHARACTERISTICS (VEE = -5.2 V ±5%) (See Note 1.)

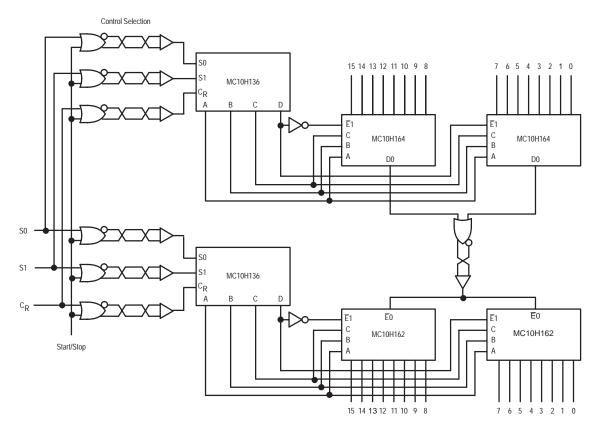
		0	0 °		25 °		75 °	
Symbol	Characteristic	Min	Max	Min	Max	Min	Мах	Unit
ΙE	Power Supply Current	-	84	-	76	-	84	mA
l _{inH}	Input Current High	-	465	-	275	-	275	μA
I _{inL}	Input Current Low	0.5	-	0.5	-	0.3	-	μA
VOH	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
VOL	Low Output Voltage	-1.95	-1.63	-1.95	-1.63	-1.95	-1.60	Vdc
VIH	High Input Voltage	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
VIL	Low Input Voltage	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc
AC PARAMETERS								
^t pd	Propagation Delay Pins 7, 9, 14 Only	0.7	2.0	0.7	2.1	0.8	2.5	ns

чра	Pins 7, 9, 14 Only Pins 2, 15 Only	0.7 0.8	2.0 2.3	0.7 0.8	2.1 2.4	0.8 0.9	2.5 2.6	115
tr	Rise Time	0.6	1.8	0.6	1.9	0.6	2.0	ns
tf	Fall Time	0.6	1.8	0.6	1.9	0.6	2.0	ns

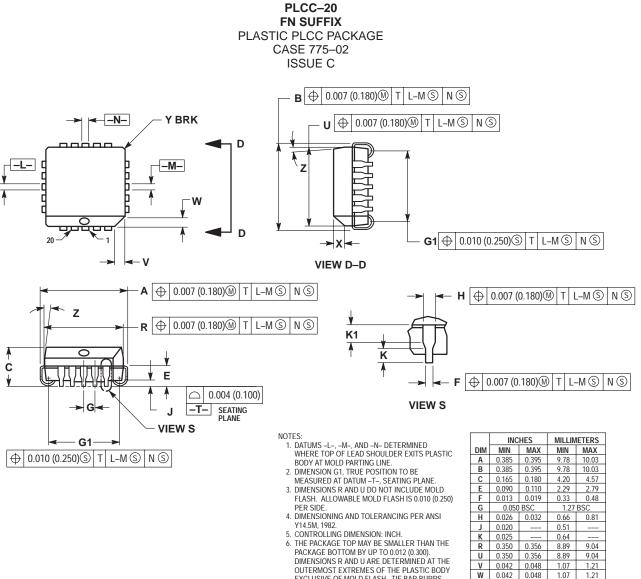
1. Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

TYPICAL APPLICATIONS

FIGURE 1 – HIGH SPEED 16-BIT MULTIPLEXER/DEMULTIPLEXER



PACKAGE DIMENSIONS



PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY. 2 DIMENSION H DOPS NOT INCLUDE DAMBAR

1.42

0.50

10 °

8.38

1.07

7.88

1.02

X 0.042 Y ----

K1 0.040

2° 10°

G1 0.310 0.330

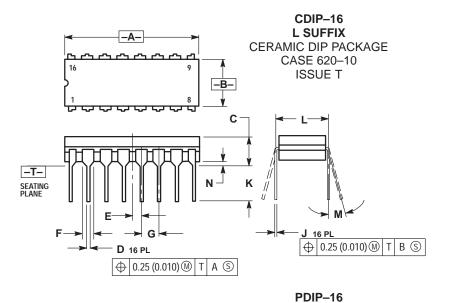
Ζ

0.056

0.020

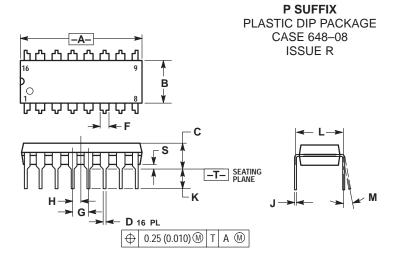
AND BOTTOM OF THE PLASTIC BODY. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL. 4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIMETERS			
DIM	MIN MAX		MIN	MAX		
Α	0.750	0.785	19.05	19.93		
В	0.240	0.295	6.10	7.49		
С		0.200		5.08		
D	0.015	0.020	0.39	0.50		
Ε	0.050 BSC		1.27 BSC			
F	0.055	0.065	1.40	1.65		
G	0.100	BSC	2.54 BSC			
Н	0.008	0.015	0.21	0.38		
К	0.125 0.170		3.18	4.31		
L	0.300 BSC		7.62	BSC		
М	0 °	15°	0 °	15 °		
Ν	0.020 0.040		0.51	1.01		



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS			
DIM	MIN MAX		MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54 BSC			
Н	0.050	BSC	1.27	BSC		
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80 7.50	3.30		
L	0.295	0.305		7.74		
М	0°	10 °	0 °	10 °		
S	0.020	0.040	0.51	1.01		

Notes

Notes

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